NSN 5961-01-505-4443

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-505-4443

| End Application: |
|--|
| An/gpn-22 radar system |
| Mounting Method: |
| Unthreaded hole |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 40.0 breakdown voltage, collector-to-base, emitter open |
| Special Features: |
| I (c) abs. (a) collector current 250m; absolute max. Power dissipated 7.5w |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |